NSN 5961-01-335-8185

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-335-8185 **Inclosure Material:** Plastic **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.080 inches **End Application:** Nimitz class cvn, los angeles class ssn (688), ticonderoga class cg (47), virginia class cgn (41), forrestal class cv, arleigh burke class ddg, spruance class dd (963), kidd class ddg, austin ship class lpd-4 amphibious transport docks. Landing craft air cushion (lcac). **Mounting Method:** Terminal **Criticality Code Justification: Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 breakdown voltage, dc **Current Rating Per Characteristic:** 200.00 nanoamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Weapon system essential; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No